

isc N-Channel MOSFET Transistor

TK65G10N1

• FEATURES

- Low drain-source on-resistance:
 $R_{DS(on)} \leq 4.5\text{m}\Omega$. ($V_{GS} = 10\text{ V}$)
- Enhancement mode:
 $V_{th} = 2.0$ to 4.0V ($V_{DS} = 10\text{ V}$, $I_D = 1.0\text{mA}$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

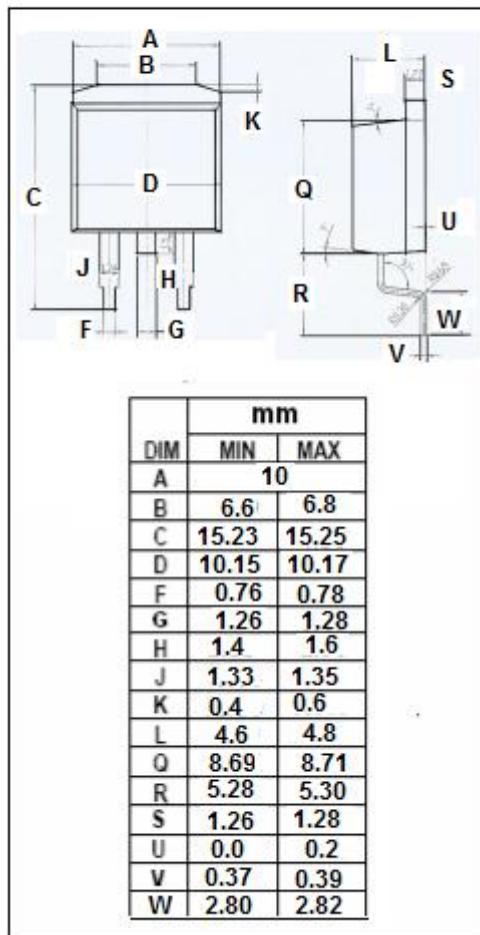
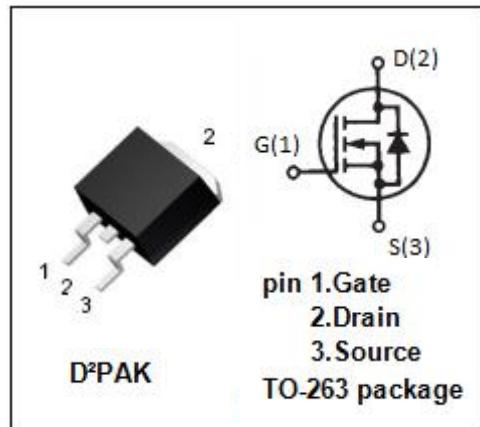
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	65	A
I_{DM}	Drain Current-Single Pulsed	283	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	156	W
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.8	$^\circ\text{C}/\text{W}$



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D=10\text{mA}$	100			V
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=10\text{V}; \text{I}_D=1.0\text{mA}$	2.0		4.0	V
$\text{R}_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}=10\text{V}; \text{I}_D=32.5\text{A}$			4.5	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			± 0.1	μA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}=100\text{V}; \text{V}_{\text{GS}}= 0\text{V}$			10	μA
V_{SDF}	Diode forward voltage	$\text{I}_{\text{DR}} = 65\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.2	V

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